

L Number	Hits	Search Text	DB	Time stamp
41	80239	peripheral near2 (circuit area region)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 15:55
42	1397599	photodiode photosensor photodector sensor	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 15:56
43	51774	(interlevel inter-level interlayer\$2 inter-layer\$2) near (dielectric insulat\$3)	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 15:57
44	715	(peripheral near2 (circuit area region) ) and (photodiode photosensor photodector sensor) and ((interlevel inter-level interlayer\$2 inter-layer\$2) near (dielectric insulat\$3))	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 15:57